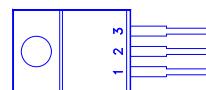
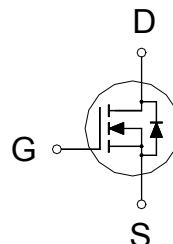


NIKO-SEM
**N-Channel Enhancement Mode
Field Effect Transistor**
P0508AT
TO-220
Halogen-Free & Lead-Free
PRODUCT SUMMARY

| $V_{(BR)DSS}$ | $R_{DS(ON)}$ | I_D |
|---------------|--------------|-------|
| 80V | 5.5mΩ | 94A |


1. GATE
2. DRAIN
3. SOURCE
**ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)**

| PARAMETERS/TEST CONDITIONS | SYMBOL | LIMITS | UNITS |
|--|----------------|------------|-------|
| Drain-Source Voltage | V_{DS} | 80 | V |
| Gate-Source Voltage | V_{GS} | ± 25 | V |
| Continuous Drain Current ² | I_D | 94 | A |
| | | 60 | |
| Pulsed Drain Current ¹ | I_{DM} | 270 | A |
| Avalanche Current | I_{AS} | 96 | |
| Avalanche Energy | E_{AS} | 460 | mJ |
| Power Dissipation | P_D | 113 | W |
| | | 45 | |
| Operating Junction & Storage Temperature Range | T_j, T_{stg} | -55 to 150 | °C |

THERMAL RESISTANCE RATINGS

| THERMAL RESISTANCE | SYMBOL | TYPICAL | MAXIMUM | UNITS |
|---------------------|-----------------|---------|---------|--------|
| Junction-to-Case | $R_{\theta JC}$ | 1.1 | 62.5 | °C / W |
| Junction-to-Ambient | $R_{\theta JA}$ | | | |

¹Pulse width limited by maximum junction temperature.²Package limitation current is 85A.**ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, Unless Otherwise Noted)**

| PARAMETER | SYMBOL | TEST CONDITIONS | LIMITS | | | UNITS |
|---------------------------------|---------------------|--|--------|-----|-----------|---------------|
| | | | MIN | TYP | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu\text{A}$ | 80 | | | V |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 2 | 3 | 4 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 25V$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 64V, V_{GS} = 0V$ | | | 1 | μA |
| | | $V_{DS} = 60V, V_{GS} = 0V, T_J = 125^\circ\text{C}$ | | | 10 | |

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| | | | | | |
|---|------------------|---------------------------------------|------|-----|-----------|
| Drain-Source On-State Resistance ¹ | $R_{DS(ON)}$ | $V_{GS} = 7V, I_D = 20A$ | 4.4 | 7 | $m\Omega$ |
| | | $V_{GS} = 10V, I_D = 20A$ | 3.9 | 5.5 | |
| Forward Transconductance ¹ | g_{fs} | $V_{DS} = 10V, I_D = 20A$ | 66 | | S |
| DYNAMIC | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$ | 3876 | | pF |
| Output Capacitance | C_{oss} | | 851 | | |
| Reverse Transfer Capacitance | C_{rss} | | 333 | | |
| Gate Resistance | R_g | $V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$ | 1.3 | | Ω |
| Total Gate Charge ² | $Q_{g(VGS=10V)}$ | $V_{DS} = 40V, I_D = 20A$ | 80 | | nC |
| | $Q_{g(VGS=7V)}$ | | 61.5 | | |
| Gate-Source Charge ² | Q_{gs} | | 17 | | |
| Gate-Drain Charge ² | Q_{gd} | | 30 | | |
| Turn-On Delay Time ² | $t_{d(on)}$ | | 74 | | nS |
| Rise Time ² | t_r | | 70 | | |
| Turn-Off Delay Time ² | $t_{d(off)}$ | | 98 | | |
| Fall Time ² | t_f | | 42 | | |
| SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_J = 25^\circ C$) | | | | | |
| Continuous Current | I_S | $I_F = 20A, V_{GS} = 0V$ | | 80 | A |
| Forward Voltage ¹ | V_{SD} | | | 1.4 | V |
| Reverse Recovery Time | t_{rr} | | | 60 | nS |
| Reverse Recovery Charge | Q_{rr} | | | 103 | nC |

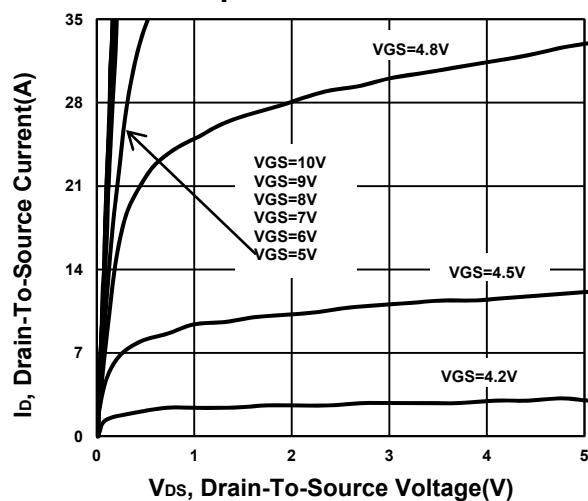
¹Pulse test : Pulse Width $\leq 300 \mu sec$, Duty Cycle $\leq 2\%$.²Independent of operating temperature.

NIKO-SEM

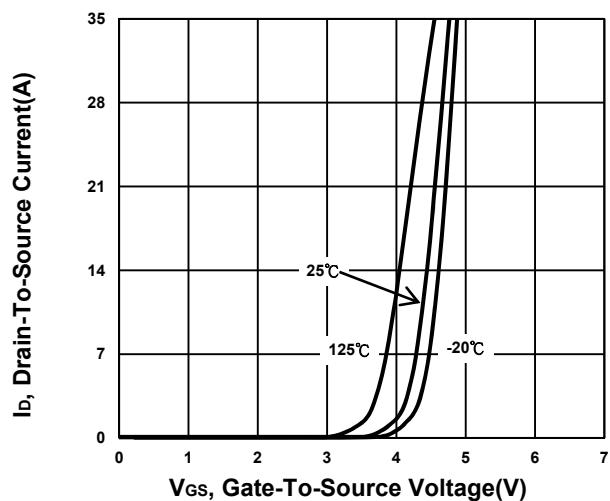
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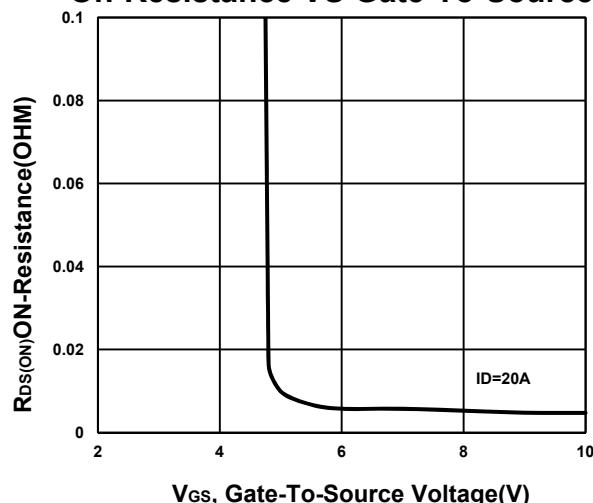
Output Characteristics



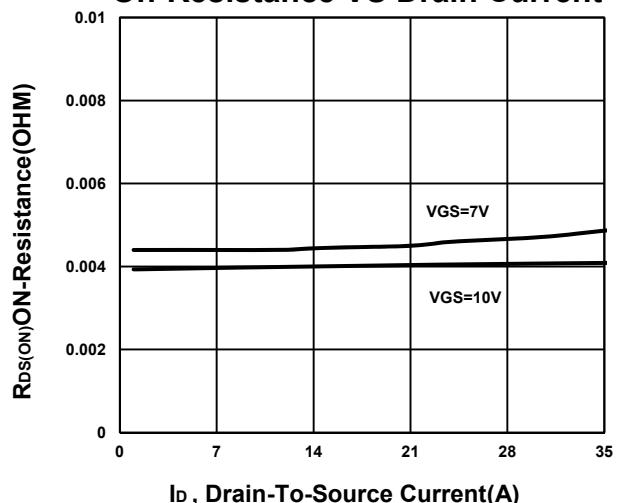
Transfer Characteristics



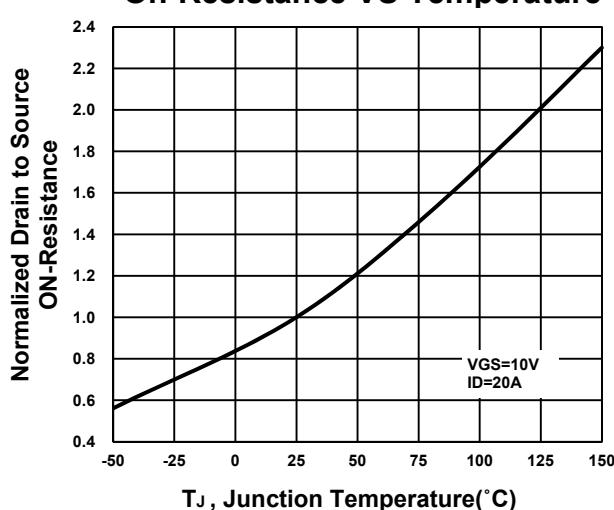
On-Resistance VS Gate-To-Source



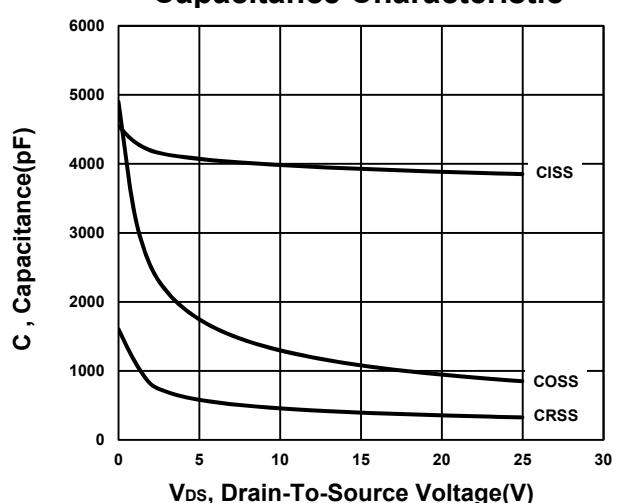
On-Resistance VS Drain Current



On-Resistance VS Temperature



Capacitance Characteristic

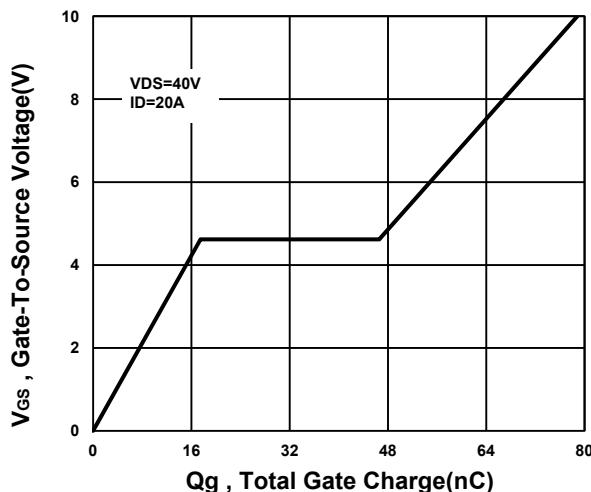


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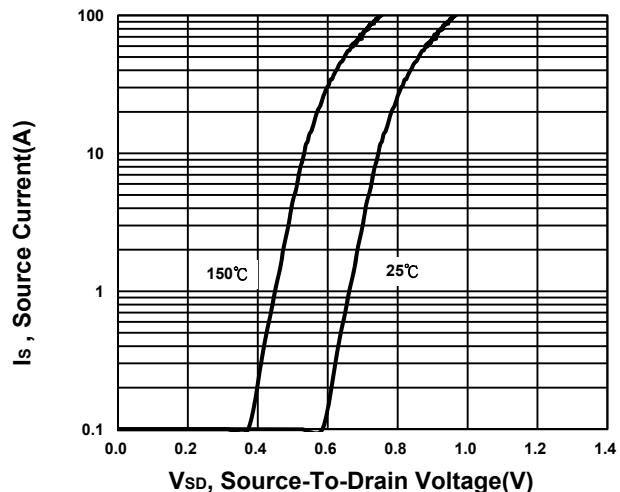
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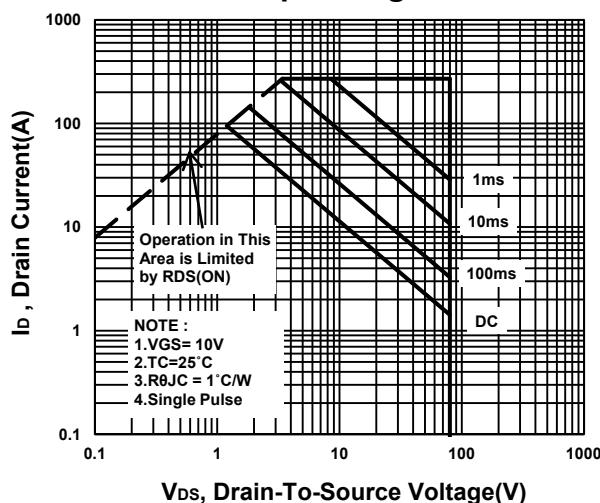
Gate charge Characteristics



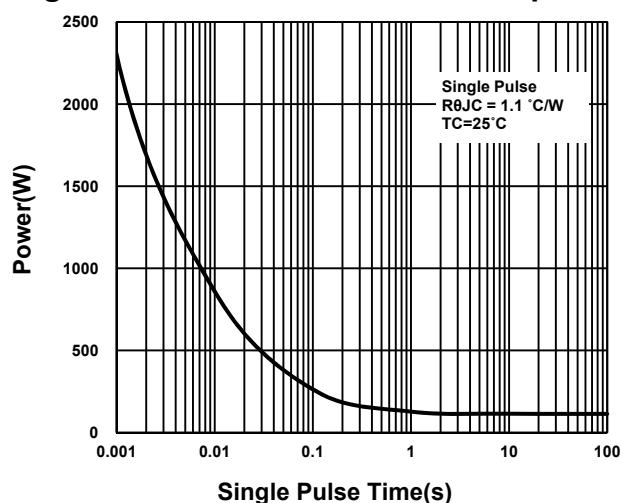
Source-Drain Diode Forward Voltage



Safe Operating Area



Single Pulse Maximum Power Dissipation



Transient Thermal Response Curve

